

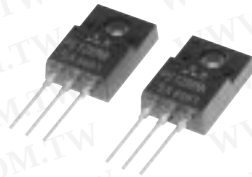
PRELIMINARY
Notice: This is not a final specification.
Some parametric limits are subject to change.

MITSUBISHI Nch POWER MOSFET

FS12KMA-5A

HIGH-SPEED SWITCHING USE

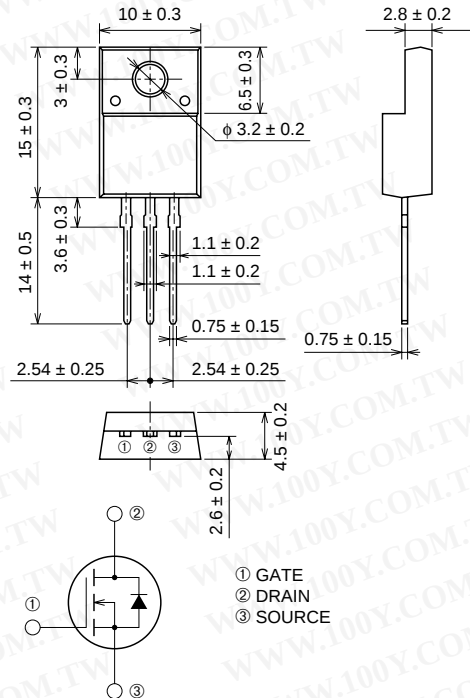
FS12KMA-5A



- 10V DRIVE
- V_{DS} 250V
- $r_{DS(ON)}$ (MAX) 0.40Ω
- I_D 12A

OUTLINE DRAWING

Dimensions in mm



TO-220FN

APPLICATION

Cs Switch for CRT Display monitor

勝特力材料 886-3-5753170
勝特力电子(上海) 86-21-54151736
勝特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)

MAXIMUM RATINGS (Tc = 25°C)

Symbol	Parameter	Conditions	Ratings	Unit
V_{DS}	Drain-source voltage	$V_{GS} = 0V$	250	V
V_{GSS}	Gate-source voltage	$V_{DS} = 0V$	± 20	V
I_D	Drain current		12	A
I_{DM}	Drain current (Pulsed)		36	A
I_{DA}	Avalanche drain current (Pulsed)	$L = 200\mu H$	12	A
P_D	Maximum power dissipation		35	W
T_{ch}	Channel temperature		$-55 \sim +150$	°C
T_{stg}	Storage temperature		$-55 \sim +150$	°C
V_{iso}	Isolation voltage	AC for 1minute, Terminal to case	2000	V
—	Weight	Typical value	2.0	g

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ELECTRICAL CHARACTERISTICS (Tch = 25°C)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
V (BR) DSS	Drain-source breakdown voltage	Id = 1mA, Vgs = 0V	250	—	—	V
IGSS	Gate-source leakage current	Vgs = ±20V, Vds = 0V	—	—	±10	μA
IDSS	Drain-source leakage current	Vds = 250V, Vgs = 0V	—	—	1	mA
VGS (th)	Gate-source threshold voltage	Id = 1mA, Vds = 10V	2.0	3.0	4.0	V
rDS (ON)	Drain-source on-state resistance	Id = 6A, Vgs = 10V	—	0.27	0.40	Ω
VDS (ON)	Drain-source on-state voltage	Id = 6A, Vgs = 10V	—	1.62	2.40	V
yfs	Forward transfer admittance	Id = 6A, Vds = 10V	—	11.0	—	S
Ciss	Input capacitance	Vds = 25V, Vgs = 0V, f = 1MHz	—	1200	—	pF
Coss	Output capacitance		—	120	—	pF
Crss	Reverse transfer capacitance		—	30	—	pF
td (on)	Turn-on delay time		—	20	—	ns
tr	Rise time	VDD = 150V, Id = 6A, Vgs = 10V, RGEN = RGS = 50Ω	—	30	—	ns
td (off)	Turn-off delay time		—	190	—	ns
tf	Fall time		—	45	—	ns
VSD	Source-drain voltage	Is = 6A, Vgs = 0V	—	0.95	—	V
Rth (ch-c)	Thermal resistance	Channel to case	—	—	3.57	°C/W

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